

### Features

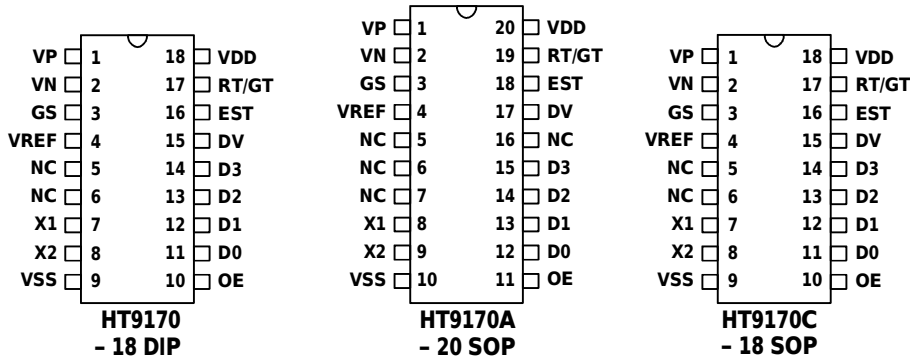
- Operating voltage: 2.5V~5.5V
- Minimal external components
- No external filter is required
- Excellent performance
- Tri-state data output for  $\mu$ C interface use
- 3.58MHz crystal or ceramic resonator

### General Description

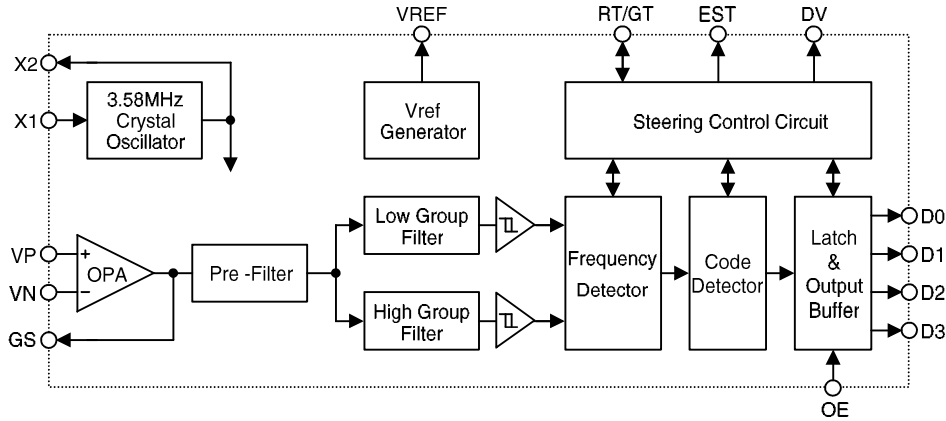
The HT9170/A/C are Dual Tone Multi Frequency (DTMF) receivers integrated with digital decoder and bandsplit filter functions. Digital counting techniques are used in the decoder to detect and decode all the 16 DTMF tone pairs into a 4-bit code output.

While the high-accuracy switched capacitor filters are employed to divide tone (DTMF) signal into low and high group signals. A built-in dial tone rejection circuit is provided to eliminate the need for pre-filtering.

### Pin Assignment



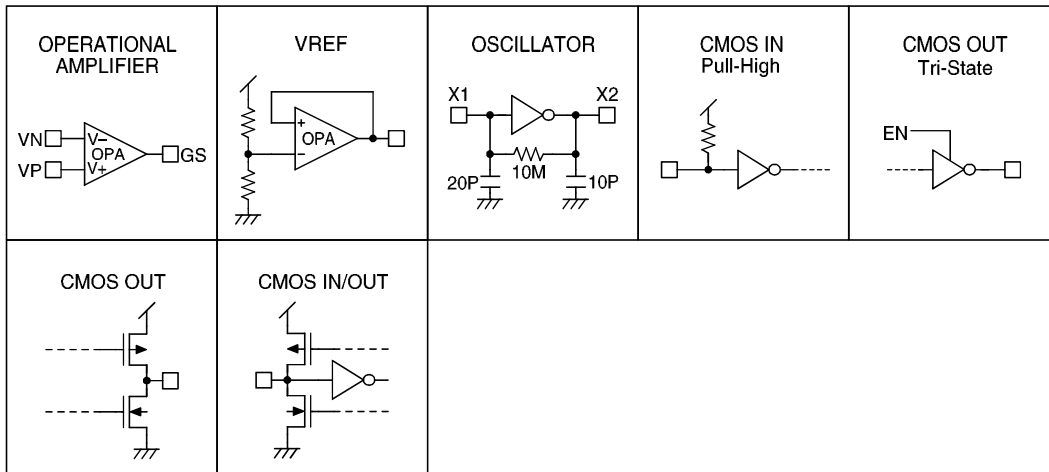
**Block Diagram**



**Pin Description**

Pin Name	I/O	Internal Connection	Description
VP	I	OPERATIONAL AMPLIFIER	Non-inverting input of operational amplifier
VN	I		Inverting input of operational amplifier
GS	O		Output terminal of operational amplifier
VREF	O	VREF	Reference voltage output, normally VDD/2
X1	I	OSCILLATOR	The system oscillator consists of an inverter, a bias resistor and the necessary load capacitor on chip. Connecting a standard 3.579545MHz crystal to X1 and X2 terminals can implement the oscillator function.
X2	O		
VSS	I	—	Negative power supply
OE	I	CMOS IN Pull-High	D0~D3 output enable, high active
D0~D3	O	CMOS OUT Tri-State	Output terminals of receiving data OE="H": Output enable OE="L": High impedance
DV	O	CMOS OUT	Data valid output When the chip receives a valid tone (DTMF) signal the DV goes high; otherwise the DV remains low.
EST	O	CMOS OUT	Early steering output (see Functional Description)
RT/GT	I/O	CMOS IN/OUT	Tone acquisition time and release time can be set through connection with external resistor and capacitor.
VDD	I	—	Positive power supply, 2.5V~5.5V for normal operation

**Approximate internal connection circuits**



**Absolute Maximum Ratings**

Supply Voltage ..... -0.3V to 6V      Storage Temperature ..... -50°C to 125°C  
 Input Voltage .....  $V_{SS}-0.3V$  to  $V_{DD}+0.3V$       Operating Temperature ..... -20°C to 75°C

**Electrical Characteristics**

DC electrical characteristic

( $T_a=25^\circ C$ )

Symbol	Parameter	Test Condition		Min.	Typ.	Max.	Unit
		V <sub>DD</sub>	Condition				
V <sub>DD</sub>	Operation Voltage	—	—	2.5	5	5.5	V
I <sub>DD</sub>	Operation Current	5V	—	—	3.0	7	mA
V <sub>IL</sub>	"Low" Input Voltage	5V	—	—	—	1.0	V
V <sub>IH</sub>	"High" Input Voltage	5V	—	4.0	—	—	V
I <sub>IL</sub>	"Low" Input Current	5V	V <sub>VP</sub> =V <sub>VN</sub> =0V	—	—	0.1	μA
I <sub>IH</sub>	"High" Input Current	5V	V <sub>VP</sub> =V <sub>VN</sub> =5V	—	—	0.1	μA
R <sub>OE</sub>	Pull-High Resistance (OE)	5V	V <sub>OE</sub> =0V	60	100	150	KΩ
R <sub>IN</sub>	Input Impedance (VN, VP)	5V	—	—	10	—	MΩ
I <sub>OH</sub>	Source Current (D0~D3, EST, DV)	5V	V <sub>OUT</sub> =4.5V	-0.4	-0.8	—	mA
I <sub>OL</sub>	Sink Current (D0~D3, EST, DV)	5V	V <sub>OUT</sub> =0.5V	1.0	2.5	—	mA
F <sub>OSC</sub>	System Frequency	5V	Crystal=3.5795MHz	3.5759	3.5795	3.5831	MHz

**Gain setting amplifier electrical characteristic**

(Ta=25°C)

Symbol	Parameter	Test Condition		Min.	Typ.	Max.	Unit
		V <sub>DD</sub>	Condition				
R <sub>IN</sub>	Input Resistance	5V	—	—	10	—	MΩ
I <sub>IN</sub>	Input Leakage Current	5V	V <sub>SS</sub> <(V <sub>VP</sub> ,V <sub>VN</sub> )<V <sub>DD</sub>	—	0.1	—	μA
V <sub>OS</sub>	Offset Voltage	5V	—	—	±25	—	mV
PSRR	Power Supply Rejection	5V	100 Hz -3V<V <sub>IN</sub> <3V	—	60	—	dB
CMRR	Common Mode Rejection	5V		—	60	—	dB
A <sub>VO</sub>	Open Loop Gain	5V		—	65	—	dB
f <sub>T</sub>	Gain Band Width	5V	—	—	1.5	—	MHz
V <sub>OUT</sub>	Output Voltage Swing	5V	R <sub>L</sub> >100KΩ	—	4.5	—	V <sub>PP</sub>
R <sub>L</sub>	Load Resistance (GS)	5V	—	—	50	—	KΩ
C <sub>L</sub>	Load Capacitance (GS)	5V	—	—	100	—	PF
V <sub>CM</sub>	Common Mode Range	5V	No load	—	3.0	—	V <sub>PP</sub>

**AC Electrical Characteristic: Using test circuit of Figure 1.**

(Ta=25°C)

Parameter	V <sub>DD</sub>	Min.	Typ.	Max.	Unit
Input Signal Level	3V	-36	—	-6	dBm
	5V	-29	—	1	
Twist Accept Limit (Positive)	5V	—	10	—	dB
Twist Accept Limit (Negative)	5V	—	10	—	dB
Dial Tone Tolerance	5V	—	18	—	dB
Noise Tolerance	5V	—	-12	—	dB
Third Tone Tolerance	5V	—	-16	—	dB
Frequency Deviation Acceptation	5V	—	—	±1.5	%
Frequency Deviation Rejection	5V	±3.5	—	—	%

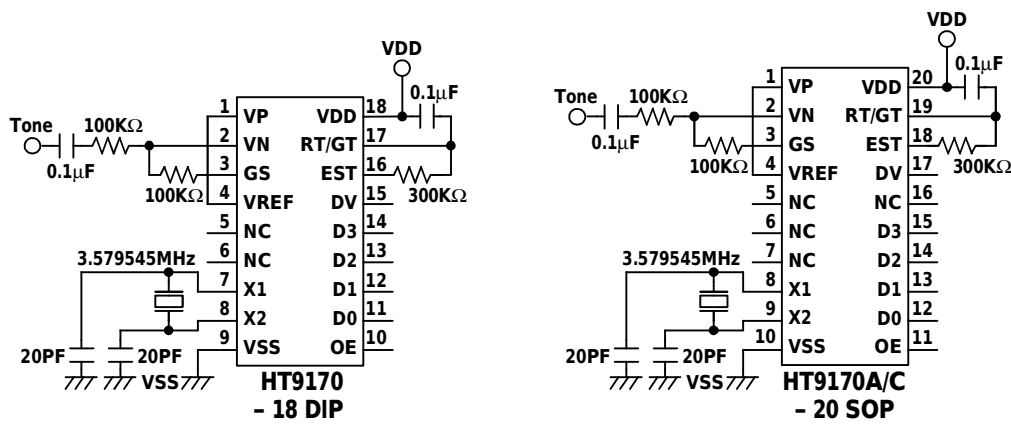


Figure 1. Test circuit

## Functional Description

### Overview

The HT9170/A/C are tone decoders. They consist of three band pass filters and two digital decode circuits to convert tone (DTMF) signal into digital code output.

An operational amplifier is built-in to adjust the input signal for users (refer to Figure 2.).

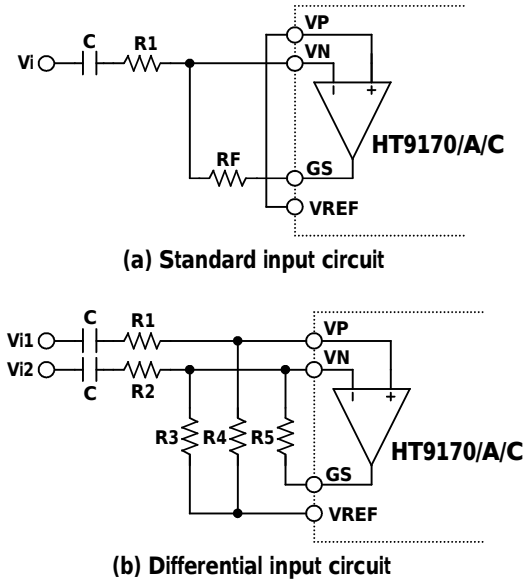


Figure 2. Input operation amplifier application circuits

The pre-filter is a band rejection filter which reduces the dialing tone which is from 350Hz to 400Hz.

The low group filter filters low group frequency signal output whereas the high group filter filters high group frequency signal output.

Each filter output is followed by a zero-crossing detector with hysteresis. When each signal amplitude at the output exceeds the specified level, it is transferred to full swing logic signal.

When input signals are recognized to be effective, DV becomes high, and the correct code of tone (DTMF) digit is transferred.

### Steering control circuit

The steering control circuit is used for measuring the effect signal duration and for protecting against the drop out of valid signals. It employs the analog delay by external RC time-constant controlled by EST.

The timing is shown in Figure 3. The EST pin is normally low and draws the RT/GT pin to keep low through discharge of external RC. When a valid tone input is detected, EST goes high to charge RT/GT through RC.

When the voltage of RT/GT changes from 0 to  $V_{TRT}$  (2.35V for 5V supply), the input signal is effective, and the correct code will be created by code detector. After D0~D3 are completely latched, DV output becomes high. When the voltage of RT/GT falls down from VDD to  $V_{TRT}$  (ie., the input tone is absent), DV output becomes low, and D0~D3 keep data until next valid tone input is yielded.

By selecting adequate external RC value the minimum acceptable input tone duration ( $t_{ACC}$ ) and the minimum acceptable inter-tone rejection ( $t_{IR}$ ) can be set by users. External components (R, C) are chosen by the formula (refer to Figure 4.):

$$t_{ACC} = t_{DP} + t_{GTP};$$

$$t_{IR} = t_{DA} + t_{GTA};$$

- where
- $t_{ACC}$ : Tone duration acceptable time
  - $t_{DP}$ : EST output delay time ("L" → "H")
  - $t_{GTP}$ : Tone present time
  - $t_{IR}$ : Inter-digit pause reject time
  - $t_{DA}$ : EST output delay time ("H" → "L")
  - $t_{GTA}$ : Tone absent time

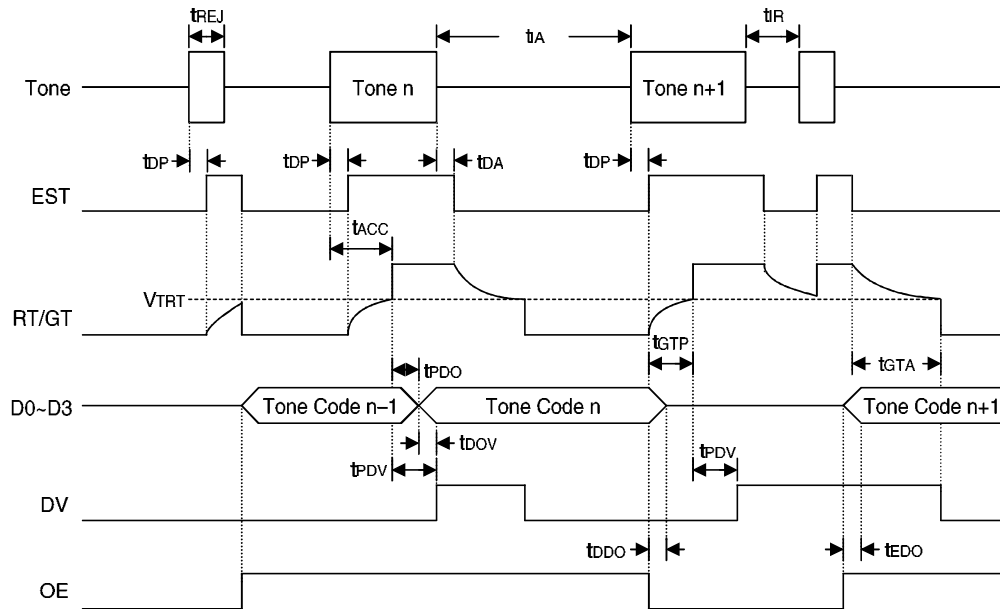


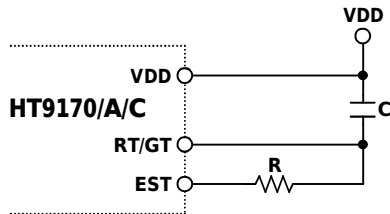
Figure 3. Steering timing

Timing Description: Using test circuit of Figure 1.

(Fosc=3.5795MHz, Ta=25°C)

Symbol	Parameter	Min.	Typ.	Max.	Units
tDP	Tone Present Detection Time	5	11	14	ms
tDA	Tone Absent Detection Time	—	4	8.5	ms
tACC	Acceptable Tone Duration	—	—	42	ms
tREJ	Rejected Tone Duration	20	—	—	ms
tIA	Acceptable Inter-digit Pause	—	—	42	ms
tIR	Rejected Inter-digit Pause	20	—	—	ms
tpDO	Propagation Delay (RT/GT to DO)	—	8	11	µs
tpDV	Propagation Delay (RT/GT to DV)	—	12	—	µs
tDOV	Output Data Set Up (DO to DV)	—	4.5	—	µs
tDDO	Disable Delay (OE to DO)	—	50	60	ns
tEDO	Enable Delay (OE to DO)	—	300	—	ns

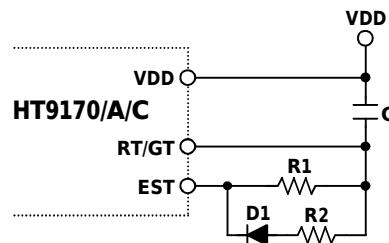
Note: DO=D0~D3.



(a) Fundamental circuit:

$$t_{GTP} = R \cdot C \cdot \ln(V_{DD} / (V_{DD} - V_{TRT}))$$

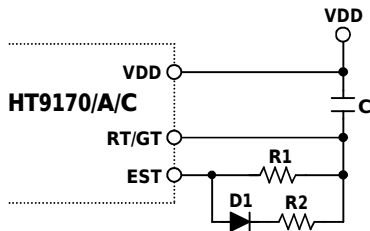
$$t_{GTA} = R \cdot C \cdot \ln(V_{DD} / V_{TRT})$$



(c)  $t_{GTP} > t_{GTA}$  :

$$t_{GTP} = R1 \cdot C \cdot \ln(V_{DD} / (V_{DD} - V_{TRT}))$$

$$t_{GTA} = (R1 // R2) \cdot C \cdot \ln(V_{DD} / V_{TRT})$$



(b)  $t_{GTP} < t_{GTA}$  :

$$t_{GTP} = (R1 // R2) \cdot C \cdot \ln(V_{DD} - V_{TRT})$$

$$t_{GTA} = R1 \cdot C \cdot \ln(V_{DD} / V_{TRT})$$

Figure 4. Steering time adjust circuits

### Tone (DTMF) Dialing Matrix

	COL1	COL2	COL3	COL4
ROW1	1	2	3	A
ROW2	4	5	6	B
ROW3	7	8	9	C
ROW4	*	0	#	D

### Tone (DTMF) Data Output Table

Low Group (Hz)	High Group (Hz)	Digit	OE	D3	D2	D1	D0
697	1209	1	H	L	L	L	H
697	1336	2	H	L	L	H	L
697	1477	3	H	L	L	H	H
770	1209	4	H	L	H	L	L
770	1336	5	H	L	H	L	H
770	1477	6	H	L	H	H	L
852	1209	7	H	L	H	H	H
852	1336	8	H	H	L	L	L
852	1477	9	H	H	L	L	H
941	1336	0	H	H	L	H	L
941	1209	*	H	H	L	H	H
941	1477	#	H	H	H	L	L
697	1633	A	H	H	H	L	H
770	1633	B	H	H	H	H	L
852	1633	C	H	H	H	H	H
941	1633	D	H	L	L	L	L
—	—	ANY	L	Z	Z	Z	Z

Z: High impedance

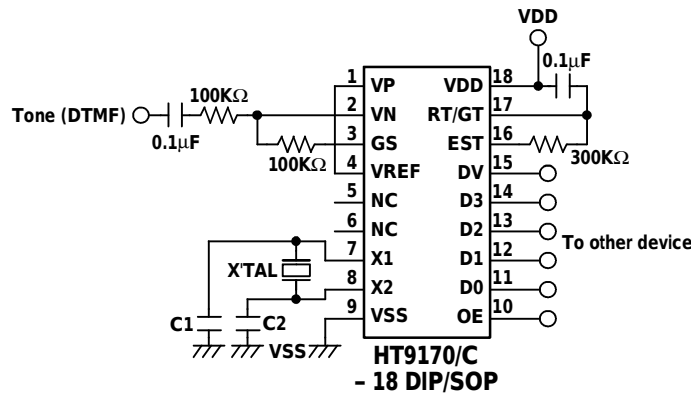
#### Data output

The data outputs (D0~D3) are tri-state outputs. When OE input becomes low, the data outputs (D0~D3) are high impedance.

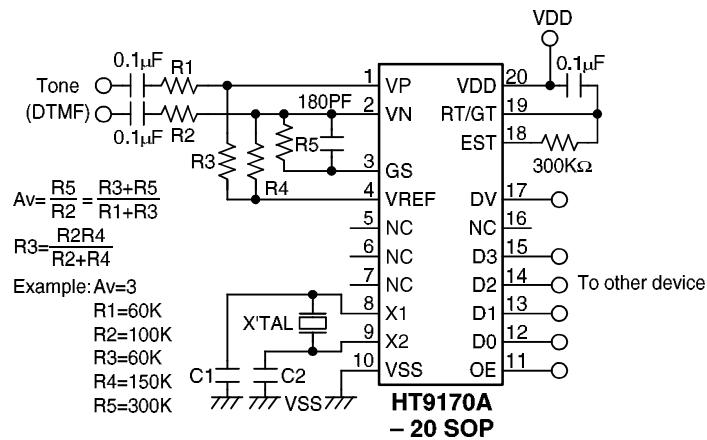


Application Circuits

Application circuit 1



Application circuit 2



Note: (a) X'TAL = 3.579545MHz crystal  
 $C_1 = C_2 \cong 20PF$

(b) X'TAL = 3.58MHz ceramic resonator  
 $C_1 = C_2 \cong 39PF$